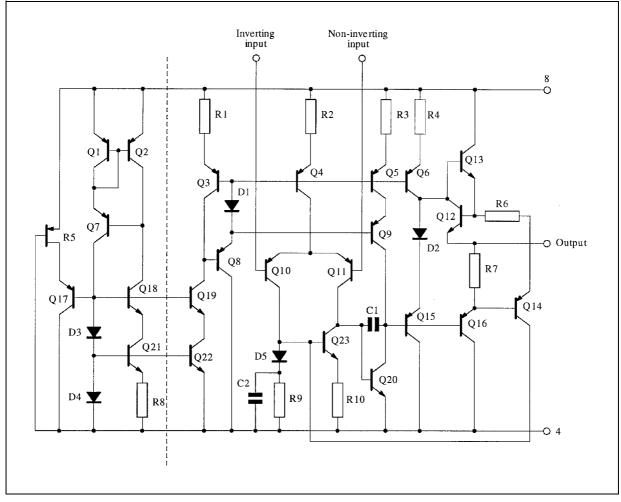
# 1 Circuit schematics







# 2 Absolute maximum ratings and operating conditions

| Symbol            | Parameter   | Value                 | Unit |
|-------------------|---|-----------------------|------|
| V <sub>CC</sub>   | Supply voltage <sup>(1)</sup>   | ±18                   | V    |
| Vi                | Input voltage <sup>(2)</sup>  | ±V <sub>CC</sub>      | V    |
| V <sub>id</sub>   | Differential input voltage <sup>(3)</sup>                             | ±(V <sub>CC</sub> -1) | V    |
| R <sub>thja</sub> | Thermal resistance junction to ambient <sup>(4)</sup><br>SO-8<br>DIP8 | 125<br>85             | °C/W |
| R <sub>thjc</sub> | Thermal resistance junction to case <sup>(4)</sup><br>SO-8<br>DIP8    | 40<br>41              | °C/W |
|                   | Output short-circuit duration <sup>(5)</sup>                          | Infinite              |      |
| Тj                | Junction temperature  | 150                   | °C   |
| T <sub>stg</sub>  | Storage temperature range   | -65 to +150           | °C   |
|                   | HBM: human body model <sup>(6)</sup>                                  | 2                     | kV   |
| ESD               | MM: machine model <sup>(7)</sup>                                      | 200                   | V    |
|                   | CDM: charged device model <sup>(8)</sup>                              | 1.5                   | kV   |

### Table 1. Absolute maximum ratings

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between  $V_{CC}^+$  and  $V_{CC}^-$ .

2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- 4. Short-circuits can cause excessive heating and destructive dissipation. Values are typical.
- 5. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
- Human body model: A 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 7. Machine model: A 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5  $\Omega$ ). This is done for all couples of connected pin combinations while the other pins are floating.
- 8. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Table 2. Operating conditions

| Symbol            | Parameter                            | LS204C                 | LS204I                 | Unit |
|-------------------|--------------------------------------|------------------------|------------------------|------|
| V <sub>CC</sub>   | Supply voltage                       | 6 to                   | V                      |      |
| V <sub>icm</sub>  | Common mode input voltage range      | V <sub>DD</sub> +1.5 t | o V <sub>CC</sub> -1.5 | V    |
| T <sub>oper</sub> | Operating free-air temperature range | 0 to +70               | -40 to +105            | °C   |

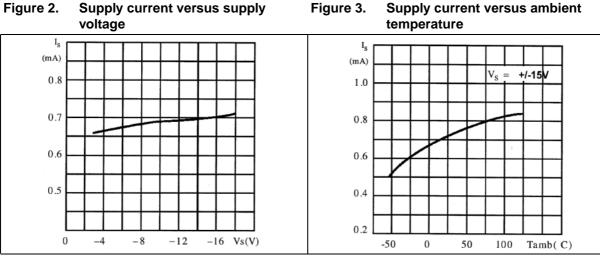


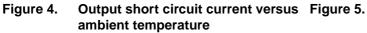
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# 3 Electrical characteristics

| Symbol                      | Parameter  |      | LS204         | 1          | I    | 11             |            |                  |
|-----------------------------|--|------|---------------|------------|------|----------------|------------|------------------|
| Зупрог                      | Farameter  | Min. | Тур.          | Max.       | Min. | Тур.           | Max.       | Unit             |
| I <sub>CC</sub>             | Supply current   |      | 0.7           | 1.2        |      | 0.8            | 1.5        | mA               |
| I <sub>ib</sub>             | Input bias current<br>T <sub>min</sub> < T <sub>amb</sub> < T <sub>max</sub>   |      | 50            | 150<br>300 |      | 100            | 300<br>700 | nA               |
| R <sub>i</sub>              | Input resistance (F = 1kHz)  |      | 1             |            |      | 1              |            | MΩ               |
| V <sub>io</sub>             | Input offset voltage ( $R_s \le 10 k\Omega$ )<br>$T_{min} < T_{amb} < T_{max}$   |      | 0.5           | 2.5<br>3.5 |      | 0.5            | 3.5<br>5   | mV               |
| $\mathrm{DV}_{\mathrm{io}}$ | Input offset voltage drift ( $R_s \le 10k\Omega$ ) $T_{min} < T_{amb} < T_{max}$   |      | 5             |            |      | 5              |            | µV/°C            |
| I <sub>io</sub>             | Input offset current<br>T <sub>min</sub> < T <sub>amb</sub> < T <sub>max</sub>   |      | 5             | 20<br>40   |      | 12             | 50<br>100  | nA               |
| DI <sub>io</sub>            | Input offset current drift T <sub>min</sub> < T <sub>amb</sub> < T <sub>max</sub>  |      | 0.08          |            |      | 0.1            |            | nA/°C            |
| I <sub>os</sub>             | Output short-circuit current   |      | 23            |            |      | 23             |            | mA               |
| A <sub>vd</sub>             | Large signal voltage gain $T_{min} < T_{amb} < T_{max}$<br>$R_L = 2k\Omega$ , $V_{CC} = \pm 15V$<br>$R_L = 2k\Omega$ , $V_{CC} = \pm 4V$ | 90   | 100<br>95     |            | 86   | 100<br>95      |            | dB               |
| GBP                         | Gain bandwidth product (F =100kHz)   | 1.8  | 3             |            | 1.5  | 2.5            |            | MHz              |
| e <sub>n</sub>              | Equivalent input noise voltage F = 1kHz, $R_s = 100\Omega$<br>$R_s = 50\Omega$<br>$R_s = 1k\Omega$<br>$R_s = 10k\Omega$                  |      | 8<br>10<br>18 |            |      | 10<br>12<br>20 |            | <u>nV</u><br>√Hz |
| THD                         | Total harmonic distortion (F = 1kHz, $A_v = 20$ dB, $R_L = 2k\Omega$ , $V_o = 2V_{pp}$ )   |      | 0.03          |            |      | 0.03           |            | %                |
| ±V <sub>opp</sub>           | Output voltage swing<br>$R_L = 2k\Omega, V_{CC} = \pm 15V$<br>$R_L = 2k\Omega, V_{CC} = \pm 4V$  | ±13  | ±3            |            | ±13  | ±3             |            | V                |
| V <sub>opp</sub>            | Large signal voltage swing $R_L = 10k\Omega$ , F= 10kHz  |      | 28            |            |      | 28             |            | V <sub>pp</sub>  |
| SR                          | Slew rate ( $R_L = 2k\Omega$ , unity gain)   | 0.8  | 1.5           |            |      | 1              |            | V/µs             |
| SVR                         | Supply voltage rejection ratio T <sub>min</sub> < T <sub>amb</sub> < T <sub>max</sub>  | 90   |               |            | 86   |                |            | dB               |
| CMR                         | Common mode rejection ratio $V_{ic} = \pm 10V$<br>$T_{min} < T_{amb} < T_{max}$  | 90   |               |            | 86   |                |            | dB               |
| $V_{01}/V_{02}$             | Channel separation (F= 1 kHz)  | 100  | 120           |            |      | 120            |            | dB               |

### Table 3.Electrical characteristics at $V_{CC} = \pm 15 \text{ V}$ , $T_{amb} = +25^{\circ} \text{ C}$ (unless otherwise specified)





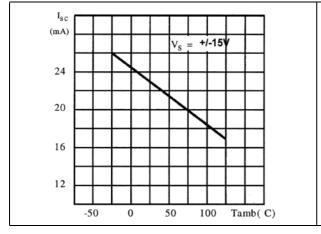


Figure 6. Output loop gain versus ambient temperature

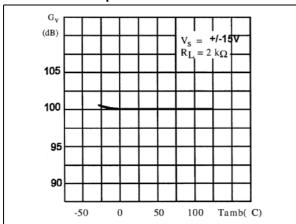
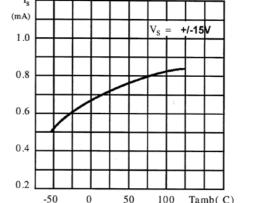


Figure 3. Supply current versus ambient



Open loop frequency and phase response

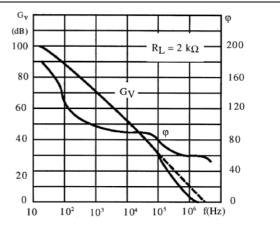
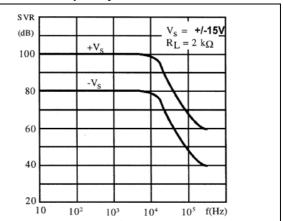
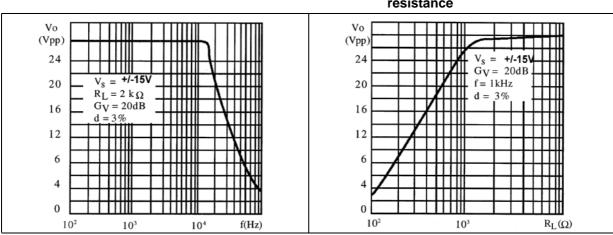
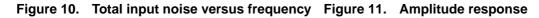


Figure 7. Supply voltage rejection versus frequency





### Figure 8. Large signal frequency response Figure 9. Output volta



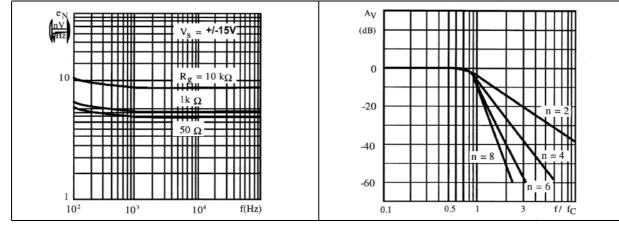
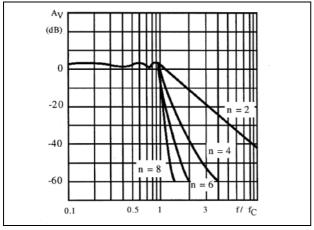
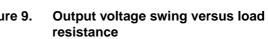


Figure 12. Amplitude response ( ±1dB ripple)







# 4 Application information for active low-pass filters

### 4.1 Butterworth

The Butterworth is a "maximally flat" amplitude response filter (Figure 11).

Butterworth filters are used for filtering signals in data acquisition systems to prevent aliasing errors in samples-data applications and for general purpose low-pass filtering.

The cut-off frequency, Fc, is the frequency at which the amplitude response is down 3 dB. The attenuation rate beyond the cut-off frequency is n6 dB per octave of frequency, where n is the order (number of poles) of the filter.

Other characteristics:

- Flattest possible amplitude response
- Excellent gain accuracy at low frequency end of passband

### 4.2 Bessel

The Bessel is a type of "linear phase" filter.

Because of their linear phase characteristics, these filters approximate a constant time delay over a limited frequency range. Bessel filters pass transient waveforms with a minimum of distortion. They are also used to provide time delays for low pass filtering of modulated waveforms and as a "running average" type filter.

The maximum phase shift is  $\frac{-n\pi}{2}$  radians,

where n is the order (number of poles) of the filter. The cut-off frequency, Fc, is defined as the frequency at which the phase shift is one half of this value.

For accurate delay, the cut-off frequency should be twice the maximum signal frequency.

*Table 4* can be used to obtain the -3 dB frequency of the filter.

Table 4. -3 dB frequency of the filter

|                 | 2 Poles                | 4 Poles | 6 Poles | 8 Poles |
|-----------------|------------------------|---------|---------|---------|
| -3 dB frequency | 3 dB frequency 0.77 Fc |         | 0.57 Fc | 0.50 Fc |

Other characteristics:

- Selectivity not as great as Chebyschev or Butterworth
- Very little overshoot response to step inputs
- Fast rise time

### 4.3 Chebyschev

Chebyschev filters have greater selectivity than either Bessel or Butterworth at the expense of ripple in the passband (*Figure 12*).

Chebyschev filters are normally designed with peak-to-peak ripple values from 0.2 dB to 2 dB.



Increased ripple in the passband allows increased attenuation above the cut-off frequency.

The cut-off frequency is defined as the frequency at which the amplitude response passes through the specified maximum ripple band and enters the stop band.

Other characteristics:

- Greater selectivity
- Very non-linear phase response
- High overshoot response to step inputs

*Table 5* shows the typical overshoot and setting time response of the low pass filters to a step input.

|                             | Number of        | Peak overshoot           | Settling t                            | ime (% of fi                           | nal value)                           |
|-----------------------------|------------------|--------------------------|---------------------------------------|--|--------------------------------------|
|                             | poles            | % Overshoot              | ±1%                                   | ±0.1%                                  | ±0.01%                               |
|                             | 2                | 4                        | 1.1Fc sec.                            | 1.7Fc sec.                             | 1.9Fc sec.                           |
| Duttomyorth                 | 4                | 11                       | 1.7/Fc                                | 2.8/Fc                                 | 3.8/Fc                               |
| Butterworth                 | 6                | 14                       | 2.4/Fc                                | 3.9S/Fc                                | 5.0S/Fc                              |
|                             | 8                | 14                       | 3.1/Fc                                | 5.1/Fc                                 | 7.1/Fc                               |
| Bessel                      | 2<br>4<br>6<br>8 | 0.4<br>0.8<br>0.6<br>0.1 | 0.8/Fc<br>1.0/Fc<br>1.3/Fc<br>1.6/Fc  | 1.4/Fc<br>1.8/Fc<br>2.1/Fc<br>2.3/Fc   | 1.7/Fc<br>2.4/Fc<br>2.7/Fc<br>3.2/Fc |
| Chebyschev (ripple ±0.25dB) | 2<br>4<br>6<br>8 | 11<br>18<br>21<br>23     | 1.1/Fc<br>3.0/Fc<br>5.9/Fc<br>8.4/Fc  | 1.6/Fc<br>5.4/Fc<br>10.4/Fc<br>16.4/Fc | -<br>-<br>-                          |
| Chebyschev (ripple ±1dB)    | 2<br>4<br>6<br>8 | 21<br>28<br>32<br>34     | 1.6/Fc<br>4.8/Fc<br>8.2/Fc<br>11.6/Fc | 2.7/Fc<br>8.4/Fc<br>16.3/Fc<br>24.8/Fc | -<br>-<br>-                          |

 Table 5.
 Overshoot and setting time response of low pass filters to step input

# 4.4 Design of 2nd order active low pass filter (Sallen and Key configuration unity gain op-amp)

For fixed R = R1 = R2, we have (see *Figure 13*):

$$C1 = \frac{1}{R} \frac{\zeta}{\omega c}$$
$$C2 = \frac{1}{R} \frac{1}{\xi \omega c}$$

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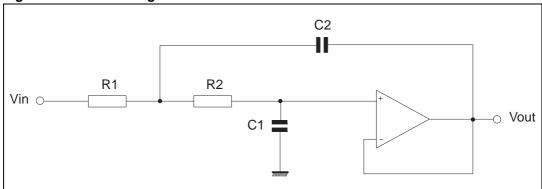


Figure 13. Filter configuration

Three parameters are needed to characterize the frequency and phase response of a 2nd order active filter:

- the gain (Gv),
- the damping factor  $(\xi)$  or the Q factor  $(Q = 2 \xi)1)$ ,
- the cut-off frequency (Fc).

The higher order response is obtained with a series of 2nd order sections. A simple RC section is introduced when an odd filter is required.

The choice of  $\xi$  (or Q factor) determines the filter response (see *Table 6*).

Table 6. Filter response to  $\xi$  or Q factor

| Filter response | ĸ                    | Q                    | Cut-off frequency (Fc)  |
|-----------------|----------------------|----------------------|---|
| Bessel          | $\frac{\sqrt{3}}{2}$ | $\frac{\sqrt{1}}{3}$ | Frequency at which phase shift is -90°C   |
| Butterworth     | $\frac{\sqrt{2}}{2}$ | $\frac{\sqrt{1}}{2}$ | Frequency at which Gv = -3 dB   |
| Chebyschev      | $\frac{\sqrt{2}}{2}$ | $\frac{\sqrt{1}}{2}$ | Frequency at which the amplitude response passes through specified max. ripple band and enters the stop bank. |



### 4.5 Example

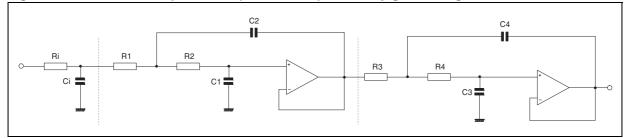


Figure 14. 5th order low-pass filter (Butterworth) with unity gain configuration

In the circuit of *Figure 14*, for Fc = 3.4 kHz and Ri = R1 = R2 = R3 = 10 kW, we obtain:

Ci = 1.354 
$$\frac{1}{R} \frac{1}{2\pi fc}$$
 = 6.33nF  
C1 = 0.421  $\frac{1}{R} \frac{1}{2\pi fc}$  = 1.97nF  
C2 = 1.753  $\frac{1}{R} \frac{1}{2\pi fc}$  = 8.20nF  
C3 = 0.309  $\frac{1}{R} \frac{1}{2\pi fc}$  = 1.45nF  
C4 = 3.325  $\frac{1}{R} \frac{1}{2\pi fc}$  = 15.14nF

The attenuation of the filter is 30 dB at 6.8 kHz and better than 60 dB at 15 kHz.

The same method, referring to *Table 7* and *Figure 15* is used to design high-pass filters. In this case the damping factor is found by taking the reciprocal of the numbers in *Table 7*.

For Fc = 5 kHz and Ci = C1 = C2 = C3 = 1 nF we obtain:

$$Ri = \frac{1}{0.354} \frac{1}{C} \frac{1}{2\pi fc} = 25.5 k\Omega$$

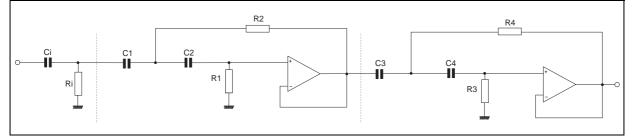
$$R1 = \frac{1}{0.421} \frac{1}{C} \frac{1}{2\pi fc} = 75.6 k\Omega$$

$$R2 = \frac{1}{1.753} \frac{1}{C} \frac{1}{2\pi fc} = 18.2 k\Omega$$

$$R3 = \frac{1}{0.309} \frac{1}{C} \frac{1}{2\pi fc} = 103 k\Omega$$

$$R4 = \frac{1}{3.325} \frac{1}{C} \frac{1}{2\pi fc} = 9.6 k\Omega$$







| Order | Ci    | C1    | C2    | C3    | C4    | C5    | C6   | C7    | C8    |
|-------|-------|-------|-------|-------|-------|-------|------|-------|-------|
| 2     |       | 0.707 | 1.41  |       |       |       |      |       |       |
| 3     | 1.392 | 0.202 | 3.54  |       |       |       |      |       |       |
| 4     |       | 0.92  | 1.08  | 0.38  | 2.61  |       |      |       |       |
| 5     | 1.354 | 0.421 | 1.75  | 0.309 | 3.235 |       |      |       |       |
| 6     |       | 0.966 | 1.035 | 0.707 | 1.414 | 0.259 | 3.86 |       |       |
| 7     | 1.336 | 0.488 | 1.53  | 0.623 | 1.604 | 0.222 | 4.49 |       |       |
| 8     |       | 0.98  | 1.02  | 0.83  | 1.20  | 0.556 | 1.80 | 0.195 | 5.125 |

 Table 7.
 Damping factor for low-pass Butterworth filters



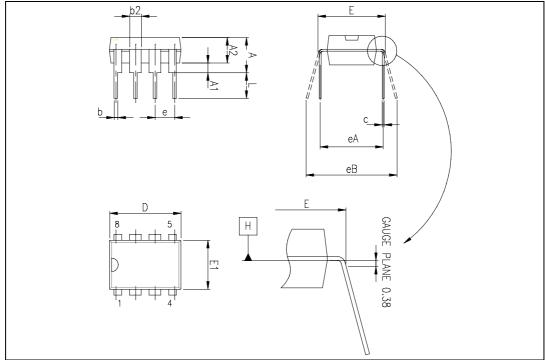
# 5 Package information

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK<sup>®</sup> packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: www.st.com.



# 5.1 DIP8 package information





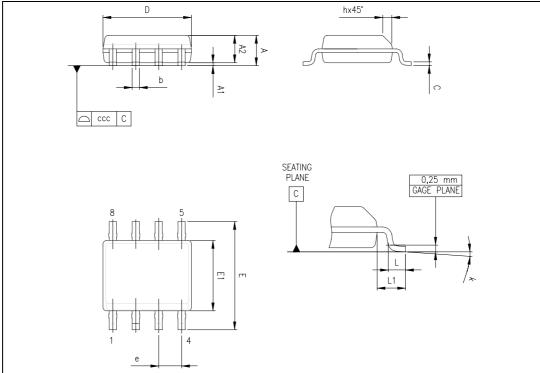
### Table 8.DIP8 package mechanical data

|      |      |             | Dime  | nsions |        |       |
|------|------|-------------|-------|--------|--------|-------|
| Ref. |      | Millimeters |       |        | Inches |       |
|      | Min. | Тур.        | Max.  | Min.   | Тур.   | Max.  |
| А    |      |             | 5.33  |        |        | 0.210 |
| A1   | 0.38 |             |       | 0.015  |        |       |
| A2   | 2.92 | 3.30        | 4.95  | 0.115  | 0.130  | 0.195 |
| b    | 0.36 | 0.46        | 0.56  | 0.014  | 0.018  | 0.022 |
| b2   | 1.14 | 1.52        | 1.78  | 0.045  | 0.060  | 0.070 |
| С    | 0.20 | 0.25        | 0.36  | 0.008  | 0.010  | 0.014 |
| D    | 9.02 | 9.27        | 10.16 | 0.355  | 0.365  | 0.400 |
| Е    | 7.62 | 7.87        | 8.26  | 0.300  | 0.310  | 0.325 |
| E1   | 6.10 | 6.35        | 7.11  | 0.240  | 0.250  | 0.280 |
| е    |      | 2.54        |       |        | 0.100  |       |
| eA   |      | 7.62        |       |        | 0.300  |       |
| eB   |      |             | 10.92 |        |        | 0.430 |
| L    | 2.92 | 3.30        | 3.81  | 0.115  | 0.130  | 0.150 |



# 5.2 SO-8 package information





### Table 9.SO-8 package mechanical data

|      |      |             | Dimer | nsions |        |       |
|------|------|-------------|-------|--------|--------|-------|
| Ref. |      | Millimeters |       |        | Inches |       |
|      | Min. | Тур.        | Max.  | Min.   | Тур.   | Max.  |
| А    |      |             | 1.75  |        |        | 0.069 |
| A1   | 0.10 |             | 0.25  | 0.004  |        | 0.010 |
| A2   | 1.25 |             |       | 0.049  |        |       |
| b    | 0.28 |             | 0.48  | 0.011  |        | 0.019 |
| С    | 0.17 |             | 0.23  | 0.007  |        | 0.010 |
| D    | 4.80 | 4.90        | 5.00  | 0.189  | 0.193  | 0.197 |
| Е    | 5.80 | 6.00        | 6.20  | 0.228  | 0.236  | 0.244 |
| E1   | 3.80 | 3.90        | 4.00  | 0.150  | 0.154  | 0.157 |
| е    |      | 1.27        |       |        | 0.050  |       |
| h    | 0.25 |             | 0.50  | 0.010  |        | 0.020 |
| L    | 0.40 |             | 1.27  | 0.016  |        | 0.050 |
| k    | 1°   |             | 8°    | 1°     |        | 8°    |
| CCC  |      |             | 0.10  |        |        | 0.004 |



# 6 Ordering information

| Table 10. Or | der codes |
|--------------|-----------|
|--------------|-----------|

| Order code  | Temperature<br>range | Package                    | Packing                | Marking  |
|---|----------------------|----------------------------|------------------------|----------|
| LS204CN   |                      | DIP8                       | Таре                   | LS204CN  |
| LS204CD<br>LS204CDT                                 | 0°C, +70°C           | SO-8                       | Tape or<br>Tape & reel | 204C     |
| LS204IN   |                      | DIP8                       | Таре                   | LS204IBN |
| LS204ID<br>LS204IDT                                 | -40°C, +105°C        | SO-8                       | Tape or<br>Tape & reel | 2041     |
| LS204IYD <sup>(1)</sup><br>LS204IYDT <sup>(1)</sup> |                      | SO-8<br>(Automotive grade) | Tape or<br>Tape & reel | 204IYD   |

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent are on-going.

# 7 Revision history

### Table 11. Document revision history

| Date        | Revision | Changes   |
|-------------|----------|---|
| 29-Nov-2001 | 1        | Initial release.  |
| 4-Jun-2008  | 2        | Updated document format.<br>Added automotive grade order codes. |



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